## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Kevin J. Ryan

Examiner:

Unknown

Serial No.:

Unknown

Group Art Unit:

Unknown

Filed:

Herewith

Docket:

303.519US2

Title: DUAL MODE DDR SDRAM/SGRAM

## INFORMATION DISCLOSURE STATEMENT

Mail Stop Patent Application **Assistant Commissioner for Patents** P.O.Box 1450 Alexandria, VA 22313-1450

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 et. seq., the enclosed materials are brought to the attention of the Examiner for consideration in connection with the above-identified patent application. Applicant respectfully requests that this Information Disclosure Statement be entered and the documents listed on the attached Form 1449 be considered by the Examiner and made of record. Pursuant to the provisions of MPEP 609, Applicant requests that a copy of the 1449 form, initialed as being considered by the Examiner, be returned to the Applicant with the next official communication.

Pursuant to 37 C.F.R. §1.97(b), it is believed that no fee or statement is required with the Information Disclosure Statement.

Pursuant to 37 C.F.R. §1.98(d), copies of the listed documents are not provided as these references were previously cited by or submitted to the U.S. Patent Office in connection with Applicant's prior U.S. application, Serial No. 09/257683, filed on February 26, 1999, which is relied upon for an earlier filing date under 35 U.S.C. §120.

The Examiner is invited to contact the Applicant's Representative at the below-listed telephone number if there are any questions regarding this communication.

Respectfully submitted,

KEVIN J. RYAN

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Date of Deposit: July 30, 2003

This paper or fee is being deposited on the date indicated above with the United States Postal Service pursuant to 37 CFR 1.10. and is addressed to The Commissioner for Patents, Mail Stop Patent Application, P.O.Box 1450, Alexandria, VA 22313-1450.

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Substitute for form 1449A/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)	Under the Paperwork Reduction Act of 1995, no persons are required to respond to a collection of information unless it contains a valid OMB control number.  Complete if Known			
	Applicati n Number	Unknown		
	Filing Dat	Even Date Herewith		
	First Named Inv ntor	Ryan, Kevin		
	Group Art Unit	Unknown		
	Examiner Nam	Unknown		
Sheet 1 of 1	Attorney Docket No: 3	303.519US2		

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**EXAMINER** 

**DATE CONSIDERED**